NSN 5961-00-496-1289



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-496-1289 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 90.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 750.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 800.0 milliwatts small-signal input power, common-collector preset **Transfer Ratio:** 40.0 small-signal short-circuit forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:**

N/a

Shelf Life:

Unit Of Measure:

80131-release3353 professional/industrial association specification

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